EN: This Datasheet/Document is presented by the manufacturer.

Please visit our website for pricing and availability at www.hestore.hu.

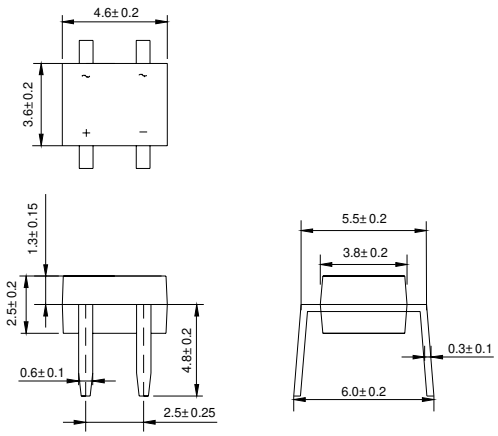
MB2M-MB10M

Silicon Bridge Rectifiers

VOLTAGE RANGE: 200 --- 1000 V
CURRENT: 0.5 A



MBM



Dimensions in millimeters

Features

- ✧ This series is UL recognized under Component Index, file number E239431
- ✧ Glass passivated chip junctions
- ✧ Plastic materrial has U/L flammability classification 94V-O
- ✧ High surge overload rating: 35A peak
- ✧ Saves space on printed circuit boards
- ✧ High temperature soldering guaranteed: 260°C/10 seconds at 5 lbs. (2.3kg) tension

Mechanical Data

- ✧ Case: Molded plastic body over passivated junctions
- ✧ Polarity: Polarity symbols marked on body
  Dimensions in inches and (millimeters)
- ✧ Mounting Position: Any
- ✧ Weight: 0.0078 ounce, 0.22 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25℃ ambient temperature unless otherwise specified.

Single phase,half wave,60 Hz,resistive or inductive load. For capacitive load,derate by 20%.

		MB2M	MB4M	MB6M	MB8M	MB10M	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	200	400	600	800	1000	V
Maximum average forw ard output current @T_A=25℃	$I_{F(AV)}$	0.5(1) 0.8(2)					A
Peak forw ard surge current 8.3ms single half-sine-w ave superimposed on rated load	I_{FSM}	35					A
Maximum instantaneous forw ard voltage @ 0.4 A	V_F	1.0					V
Maximum reverse current @T_A=25℃ at rated DC blocking voltage @T_A=125℃	I_R	5.0 100					μA
Typical junction capacitance per leg (NOTE 3)	C_J	13					pF
Typical thermal resistance per leg (NOTE 1)	$R_{\theta JA}$ $R_{\theta JL}$	85 20					℃/W
Operating junction temperature range	T_J	- 55 ---- + 150					℃
Storage temperature range	T_{STG}	- 55 ---- + 150					℃

NOTES: (1) On glass epoxy P.C.B. mounted on 0.05 x 0.05" (1.3 x 1.3mm) pads
(2) On aluminum substrate P.C.B. with an area of 0.8" x 0.8" (20 x 20mm) mounted on 0.05 x 0.05" (1.3 x 1.3mm) solder pad
(3) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts

MB2M-MB10M

Silicon Bridge Rectifiers

Ratings AND Charactieristic Curves

FIG.1 – DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

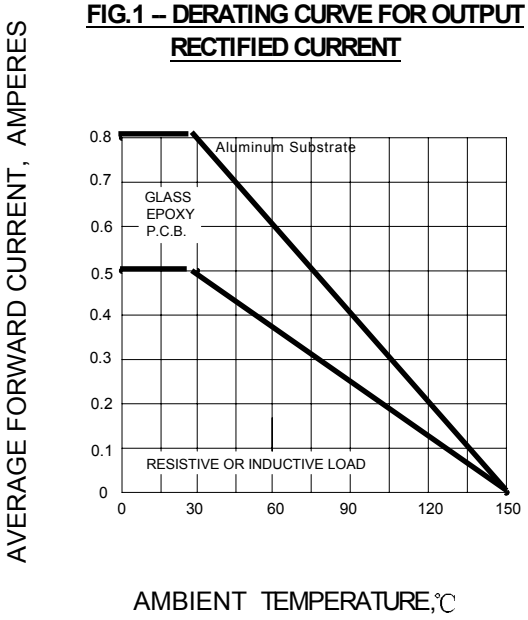


FIG.2 – MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT PER LEG

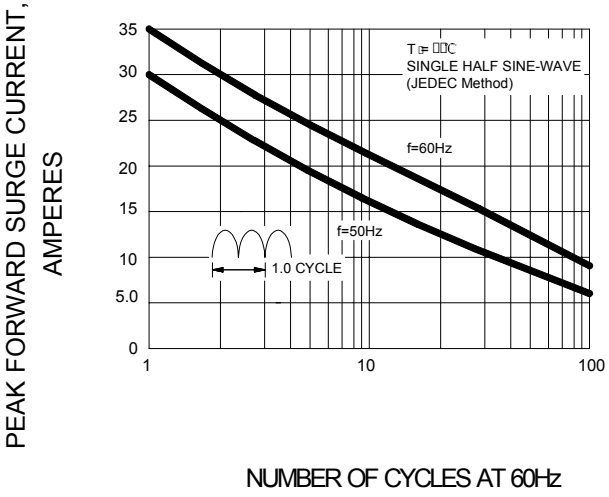


FIG.3 – TYPICAL FORWARD VOLTAGE CHARACTERISTICS PER LEG

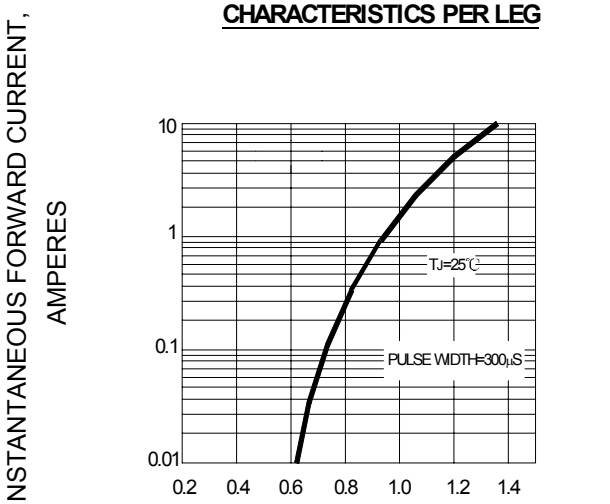


FIG.4 – TYPICAL REVERSE CHARACTERISTIC

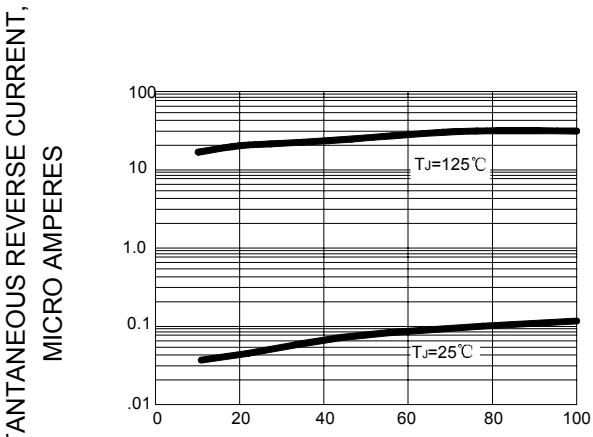


FIG.5 – TYPICAL JUNCTION CAPACITANCE PER ELEMENT

